



BUK9Y14-80E

N-channel 80 V, 15 mΩ logic level MOSFET in LPAK56

11 November 2014

Product data sheet

1. General description

Logic level N-channel MOSFET in an LPAK56 (Power SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True logic level gate with $V_{GS(th)}$ rating of greater than 0.5 V at 175 °C

3. Applications

- 12 V, 24 V and 48 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|---|-----|------|-----|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$ | - | - | 80 | V |
| I_D | drain current | $V_{GS} = 5\text{ V}$; $T_{mb} = 25\text{ °C}$; Fig. 1 | - | - | 62 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 2 | - | - | 147 | W |
| Static characteristics | | | | | | |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 5\text{ V}$; $I_D = 15\text{ A}$; $T_j = 25\text{ °C}$; Fig. 11 | - | 12.2 | 15 | mΩ |
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $V_{GS} = 5\text{ V}$; $I_D = 15\text{ A}$; $V_{DS} = 64\text{ V}$; $T_j = 25\text{ °C}$; Fig. 13 ; Fig. 14 | - | 8.7 | - | nC |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--|---|
| 1 | S | source |  <p>LPAK56; Power-SO8 (SOT669)</p> |  |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|-------------------|---|---------|
| | Name | Description | Version |
| BUK9Y14-80E | LPAK56; Power-SO8 | Plastic single-ended surface-mounted package (LPAK56; Power-SO8); 4 leads | SOT669 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BUK9Y14-80E | 91480E |

8. Limiting values

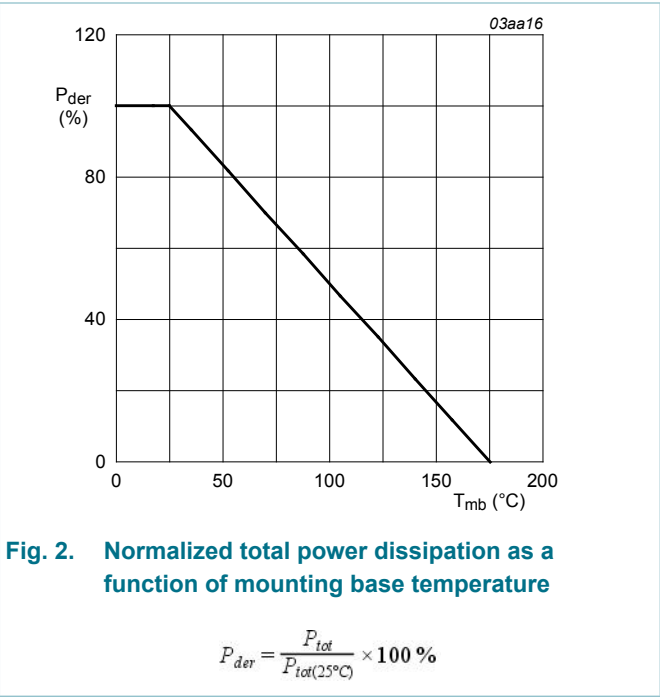
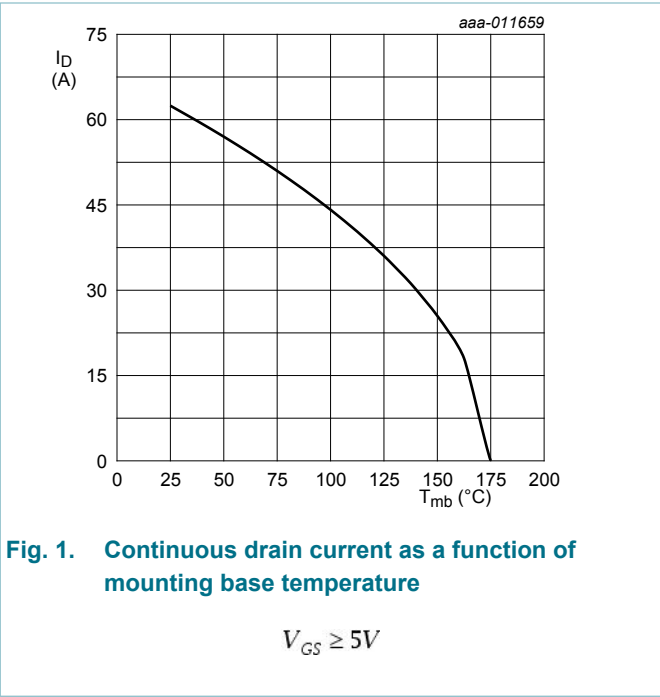
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------|-------------------------|---|--------|-----|-----|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$ | | - | 80 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20\text{ k}\Omega$ | | - | 80 | V |
| V_{GS} | gate-source voltage | $T_j \leq 175\text{ °C}$; DC | | -10 | 10 | V |
| | | $T_j \leq 175\text{ °C}$; Pulsed | [1][2] | -15 | 15 | V |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 2 | | - | 147 | W |
| I_D | drain current | $T_{mb} = 25\text{ °C}$; $V_{GS} = 5\text{ V}$; Fig. 1 | | - | 62 | A |
| | | $T_{mb} = 100\text{ °C}$; $V_{GS} = 5\text{ V}$; Fig. 1 | | - | 44 | A |
| I_{DM} | peak drain current | $T_{mb} = 25\text{ °C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4 | | - | 250 | A |

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|--|------------------------|-----|------|------|
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| T _j | junction temperature | | | -55 | 175 | °C |
| Source-drain diode | | | | | | |
| I _S | source current | T _{mb} = 25 °C | | - | 62 | A |
| I _{SM} | peak source current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C | | - | 250 | A |
| Avalanche ruggedness | | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 62 A; V _{sup} ≤ 80 V; R _{GS} = 50 Ω; V _{GS} = 5 V; T _{j(init)} = 25 °C; unclamped; Fig. 3 | [3][4] | - | 79.6 | mJ |

- [1] Accumulated pulse duration up to 50 hours delivers zero defect ppm
- [2] Significantly longer life times are achieved by lowering T_j and or V_{GS}
- [3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [4] Refer to application note AN10273 for further information.



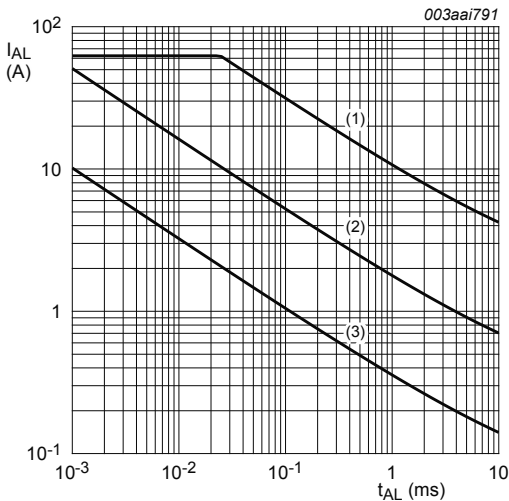


Fig. 3. Avalanche rating; avalanche current as a function of avalanche time

(1) $T_{j\ (init)} = 25^{\circ}C$; (2) $T_{j\ (init)} = 150^{\circ}C$; (3) Repetitive Avalanche

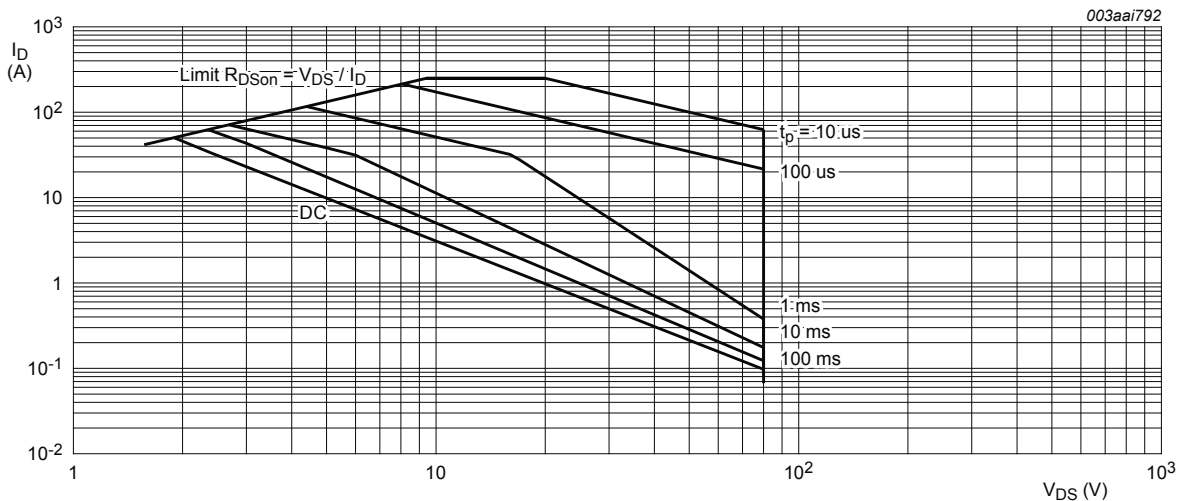


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | - | - | 1.02 | K/W |

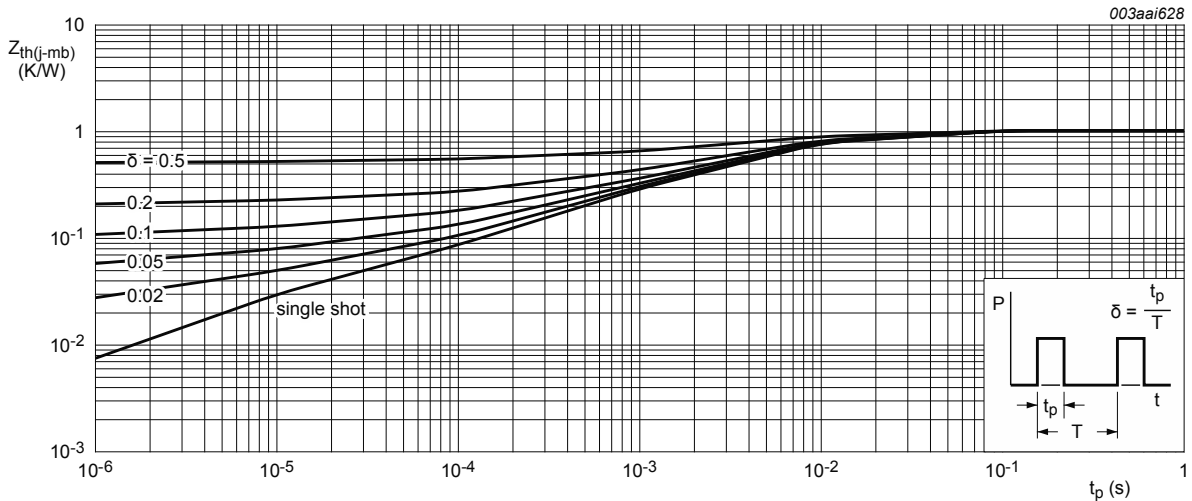


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------|---|-----|------|-------|---------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A$; $V_{GS} = 0 V$; $T_J = 25 ^\circ C$ | 80 | - | - | V |
| | | $I_D = 250 \mu A$; $V_{GS} = 0 V$; $T_J = -55 ^\circ C$ | 72 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 mA$; $V_{DS} = V_{GS}$; $T_J = 25 ^\circ C$; Fig. 9 ; Fig. 10 | 1.4 | 1.7 | 2.1 | V |
| | | $I_D = 1 mA$; $V_{DS} = V_{GS}$; $T_J = -55 ^\circ C$; Fig. 9 | - | - | 2.45 | V |
| | | $I_D = 1 mA$; $V_{DS} = V_{GS}$; $T_J = 175 ^\circ C$; Fig. 9 | 0.5 | - | - | V |
| I_{DSS} | drain leakage current | $V_{DS} = 80 V$; $V_{GS} = 0 V$; $T_J = 25 ^\circ C$ | - | 0.25 | 10 | μA |
| I_{DSS} | drain leakage current | $V_{DS} = 80 V$; $V_{GS} = 0 V$; $T_J = 175 ^\circ C$ | - | - | 500 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = 10 V$; $V_{DS} = 0 V$; $T_J = 25 ^\circ C$ | - | 2 | 100 | nA |
| | | $V_{GS} = -10 V$; $V_{DS} = 0 V$; $T_J = 25 ^\circ C$ | - | 2 | 100 | nA |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 5 V$; $I_D = 15 A$; $T_J = 25 ^\circ C$; Fig. 11 | - | 12.2 | 15 | mΩ |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10 V$; $I_D = 15 A$; $T_J = 25 ^\circ C$; Fig. 11 | - | 11.3 | 14 | mΩ |
| | | $V_{GS} = 5 V$; $I_D = 15 A$; $T_J = 175 ^\circ C$; Fig. 11 ; Fig. 12 | - | - | 37.65 | mΩ |

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------|------------------------------|--|--|-----|------|------|------|
| Dynamic characteristics | | | | | | | |
| Q _{G(tot)} | total gate charge | I _D = 15 A; V _{DS} = 64 V; V _{GS} = 5 V; T _j = 25 °C; Fig. 13 ; Fig. 14 | | - | 28.9 | - | nC |
| Q _{GS} | gate-source charge | | | - | 8.1 | - | nC |
| Q _{GD} | gate-drain charge | | | - | 8.7 | - | nC |
| C _{iss} | input capacitance | V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz; T _j = 25 °C; Fig. 15 | | - | 3479 | 4640 | pF |
| C _{oss} | output capacitance | | | - | 236 | 283 | pF |
| C _{rss} | reverse transfer capacitance | | | - | 114 | 156 | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 60 V; R _L = 4 Ω; V _{GS} = 5 V; R _{G(ext)} = 5 Ω; T _j = 25 °C | | - | 15.3 | - | ns |
| t _r | rise time | | | - | 24.6 | - | ns |
| t _{d(off)} | turn-off delay time | | | - | 45.3 | - | ns |
| t _f | fall time | | | - | 24.7 | - | ns |
| Source-drain diode | | | | | | | |
| V _{SD} | source-drain voltage | I _S = 15 A; V _{GS} = 0 V; T _j = 25 °C; Fig. 16 | | - | 0.8 | 1.2 | V |
| t _{rr} | reverse recovery time | I _S = 20 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = 25 V; T _j = 25 °C | | - | 25.8 | - | ns |
| Q _r | recovered charge | | | - | 29.3 | - | nC |

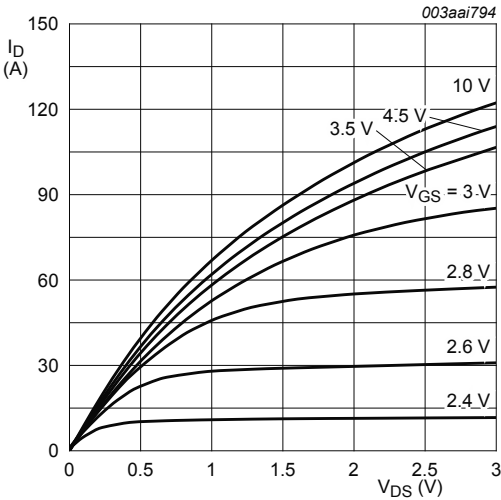


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

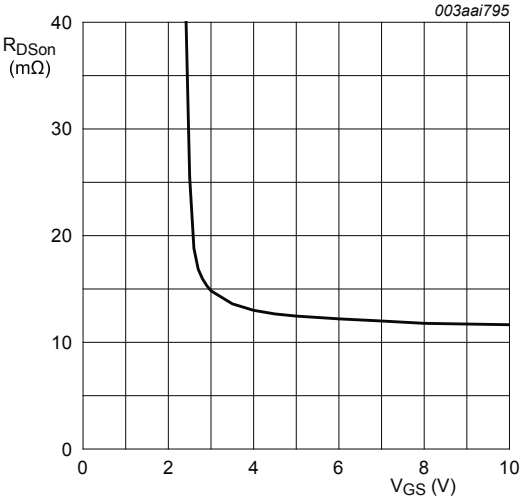


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25\text{ }^{\circ}\text{C}; I_D = 15\text{ A}$

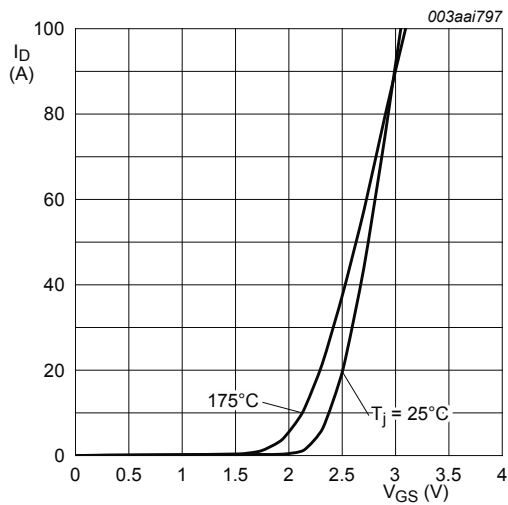


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10\text{ V}$

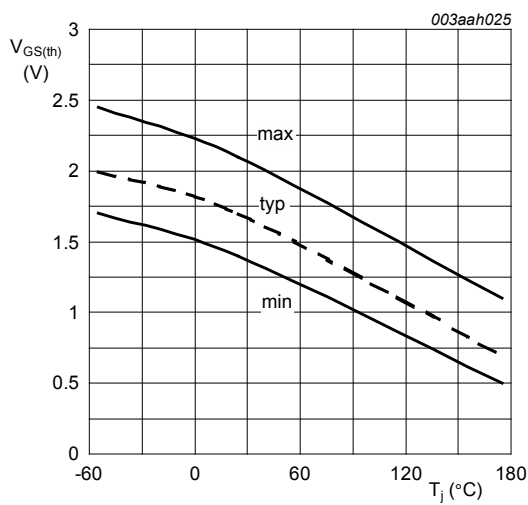


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$I_D = 1\text{ mA}; V_{DS} = V_{GS}$

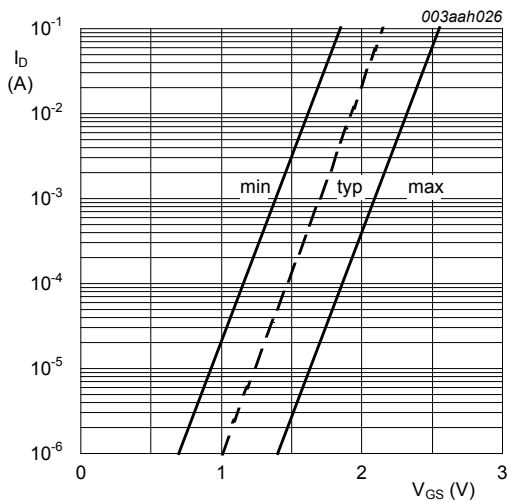
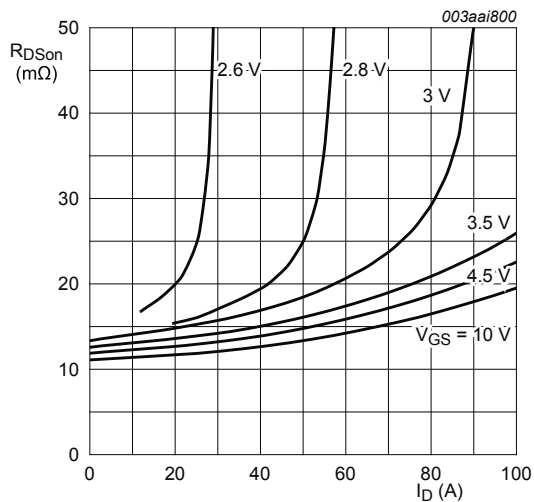


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}; V_{DS} = 5\text{ V}$



$T_j = 25^\circ\text{C}; t_p = 300\text{ }\mu\text{s}$

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

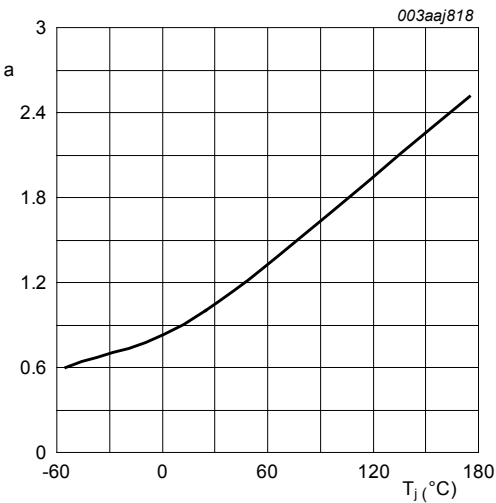


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)}(25^{\circ}\text{C})}$$

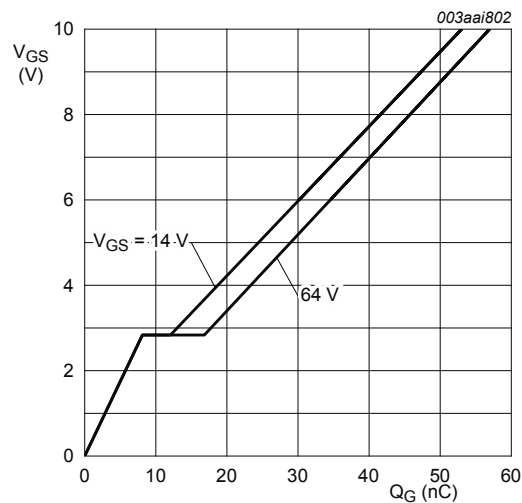


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}\text{C}; I_D = 15\text{ A}$$

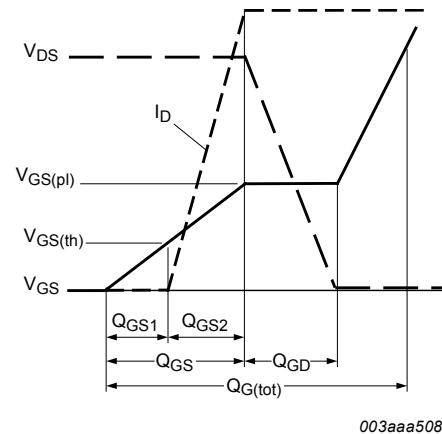


Fig. 13. Gate charge waveform definitions

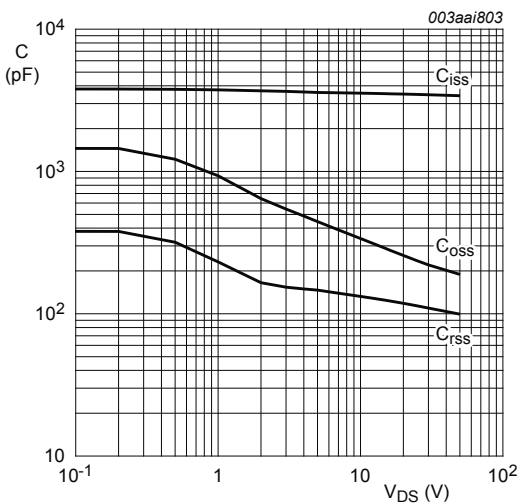


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$$

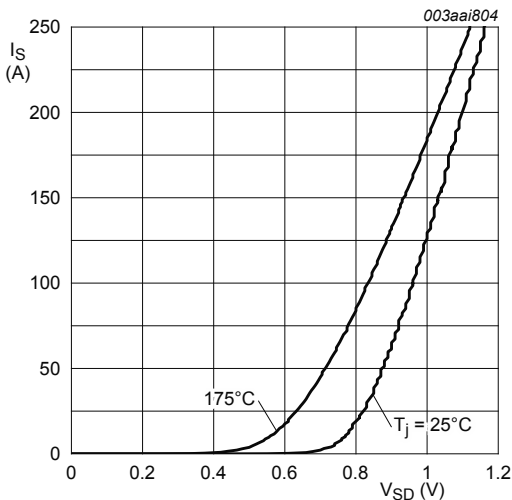


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$V_{GS} = 0V$

11. Package outline



Fig. 17. Package outline LPAK56; Power-SO8 (SOT669)

12. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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13. Contents

| | | |
|------|-------------------------------|----|
| 1 | General description | 1 |
| 2 | Features and benefits | 1 |
| 3 | Applications | 1 |
| 4 | Quick reference data | 1 |
| 5 | Pinning information | 2 |
| 6 | Ordering information | 2 |
| 7 | Marking | 2 |
| 8 | Limiting values | 2 |
| 9 | Thermal characteristics | 4 |
| 10 | Characteristics | 5 |
| 11 | Package outline | 10 |
| 12 | Legal information | 11 |
| 12.1 | Data sheet status | 11 |
| 12.2 | Definitions | 11 |
| 12.3 | Disclaimers | 11 |
| 12.4 | Trademarks | 12 |

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